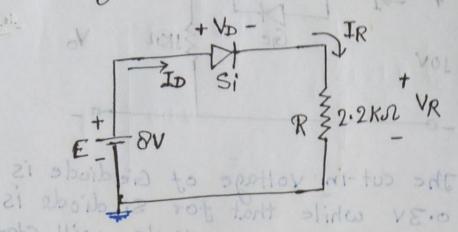
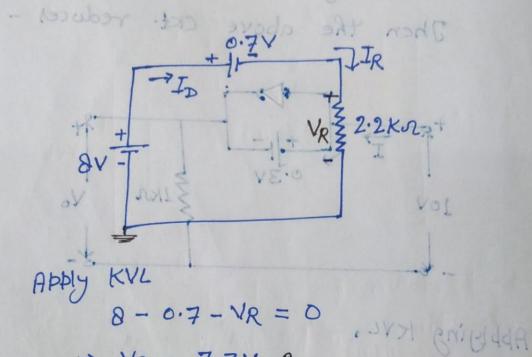
Q1. Determine Vo and I for the following circuit si \$1Ks JOV soln The cut-in voltage of Gediode is 0.34 while that for si diocle is 0.74. Hence Ge diode will start conducting first and it gots as a battery of 0.3 V Then the above ckt. reduces -31KM 104 Applying KYL, 10-0.3-1X1X103 70.4 = NV = $\Rightarrow I = \frac{9.7}{103.7} = \frac{9.7 \, \text{mA}}{103.7} \cdot \frac{\text{Ams}}{103}$:.. Vo = 9.7 mA XIKA = 9.7 V Ams.

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Q. For the series diode configuration of following ty., determine Vs. VR and ID



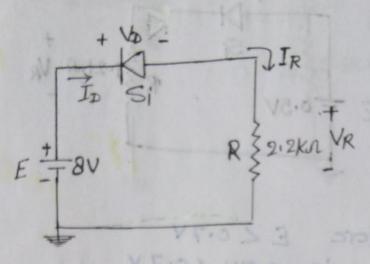
Soln- Here, diode is in the 'ON' state.



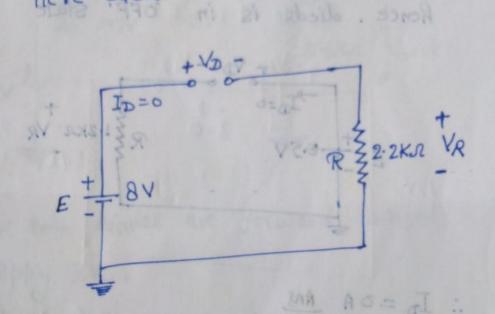
$$: I_D = I_R = \frac{1}{R} = \frac{7.3 \text{ V}}{2.2 \text{ K.s.}}$$

3.32mA Ans.

Q. For the following circuit, determine VD,



Soln Here diode 4 OFF. Then



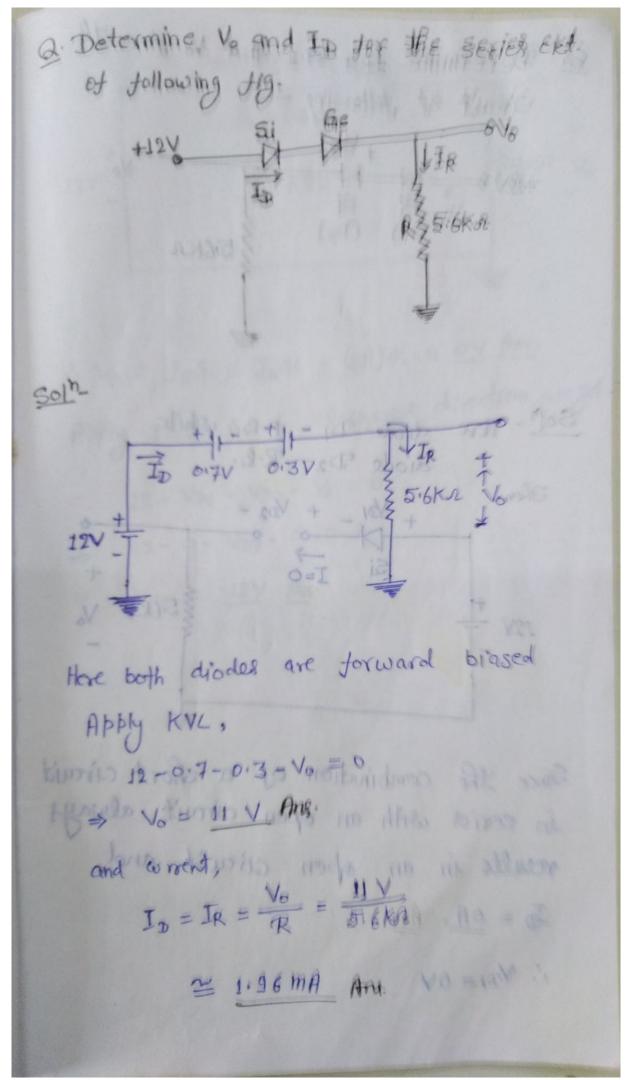
ID = OAAns

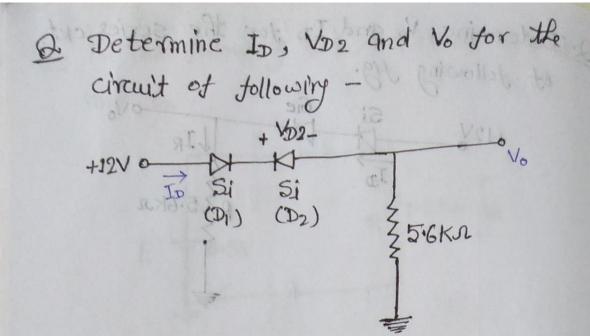
: ID = IR = 0 10 VO = 9.7 = 9V :

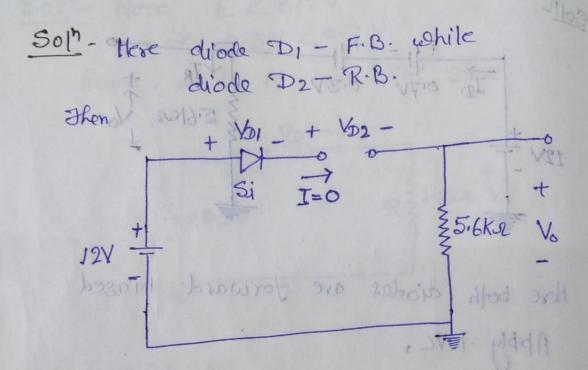
:. VR = IR. R = OV Ans.

Now, apply KVL around the closed loop -

: VD = E-VR = E-0 = E = 8 V Ams.

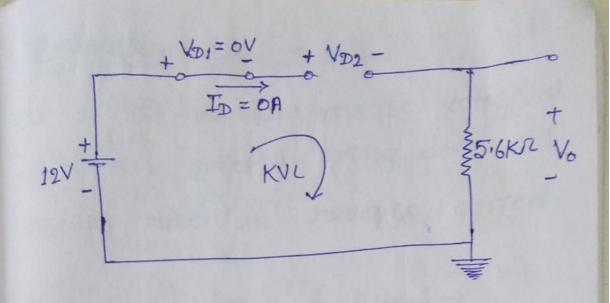






Since the combination of a short circuit in series with an open circuit always results in an open circuit and 5 = 0A. Ans

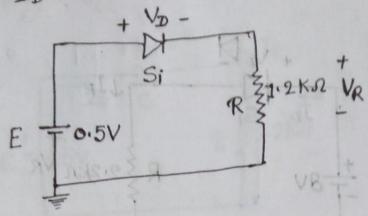
: VD1= OV MA AM 38.1 =



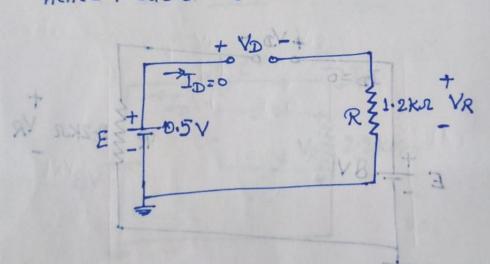
11 Vo = IR.R = ID.R = (6A).R = OV Ans.

Apply KVL in a clockwise direction, we get-

Q. For the following cxt, determine 40, VR and ID.



Sal"- Here E < 0.7 V
i.e. 0.5 V < 0.7 V
Rence. diode is in 'OFF' state



- : ID = OA Ans
- :. IR = 0A
- :. VR = IR. R = OV ANS. 0 = 91 = 1 :

and Vo = E = 0.50 Ams 9.9 = 9V

E-Va=VR=E-0=E & 8V ALLS